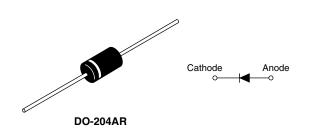


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COMPLIANT

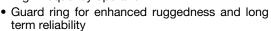
Photovoltaic Solar Cell Protection Schottky Rectifier, 15 A



PRODUCT SUMMARY				
I _{F(AV)}	15 A			
V_{R}	30 V to 45 V			

FEATURES

- 150 °C T_J operation
- Low forward voltage drop
- High frequency operation



- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- · Lead (Pb)-free plating
- Compliant to RoHS directive 2002/95/EC
- Designed and qualified for industrial level

DESCRIPTION

The VS-150SQ... axial leaded Schottky rectifier series has been optimized for very low forward voltage drop, with moderate leakage. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

 $T_J \le 200$ °C for use in solar cell box as a bypass diode for protection, using DC forward current without reverse bias.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I _{F(AV)}	DC	15	A		
V _{RRM}		30 to 45	V		
I _{FSM}	t _p = 5 µs sine	2150	A		
V _F	15 Apk, T _J = 125 °C	0.48	V		
T _J	Range (1)	- 55 to 150	°C		

Note

(1) $T_J \le 200$ °C for DC current without reverse voltage

VOLTAGE RATINGS						
PARAMETER	SYMBOL	VS-150SQ030	VS-150SQ035	VS-150SQ040	VS-150SQ045	UNITS
Maximum DC reverse voltage	V_{R}	- 30	35	40	45	V
Maximum working peak reverse voltage	V_{RWM}	30	35	40	45	V

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current See fig. 5	I _{F(AV)}	For DC solar application T _C = 172 °C (T _J = 200 °C)		15	
Maximum peak one cycle non-repetitive surge current	l	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated	2150	Α
See fig. 7	I _{FSM}	10 ms sine or 6 ms rect. pulse	V _{RRM} applied	340	
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 1.8 A, L = 7.4 mH		12	mJ
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by, T_J maximum $V_A = 1.5 \times V_R$ typical		1.8	А

VS-150SQ... Series

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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
	. V _{EM} (!)	15 A	T _J = 25 °C	0.54	
		30 A		0.67	V
Maximum forward voltage drop		15 A	T _J = 125 °C	0.48	
See fig. 1		30 A		0.62	
		15 A	- T _J = 200 °C	0.46	
		30 A		0.61	
Maximum reverse leakage current	1	T _J = 25 °C	V _B = Rated V _B	1.75	mA
See fig. 2	I _{RM}	T _J = 125 °C	v _R = nateu v _R	70	IIIA
Maximum junction capacitance	C _T	$V_R = 5 V_{DC}$, (test signal range 100 kHz to 1 MHz), 25 °C		900	pF
Typical series inductance	L _S	Measured lead to lead 5 mm from body		10.0	nH
Maximum voltage rate of change	dV/dt	Rated V _R 10 00		10 000	V/µs

Note

 $^{^{(1)}\,}$ Pulse width $<300~\mu s,$ duty cycle <2~%

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction temperature range	T _J ⁽¹⁾		- 55 to 150	°C	
Maximum storage temperature range	T _{Stg}		- 55 to 150		
Maximum thermal resistance,	R_{thJL}	DC operation; 1/8" lead length	8.0		
junction to lead	R _{thJL} ⁽²⁾		4.0	°C/W	
Typical thermal resistance, junction to air	R_{thJA}		44	3, 1,	
Approximate weight			1.4	g	
Approximate weight			0.049	oz.	
Marking device			150S	Q030	
		Case style DO-204AR (JEDEC)	150SQ035		
			150SQ040		
			1508	Q045	

Notes

 $^{^{(1)}}$ T_J = 200 °C for DC solar application without reverse voltage time ≤ 1 h

⁽²⁾ Applicable when used in junction box at $I_F = 12$ A, $T_{box} = 77$ °C



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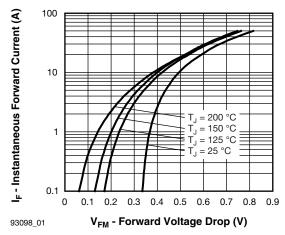


Fig. 1 - Maximum Forward Voltage Drop Characteristics

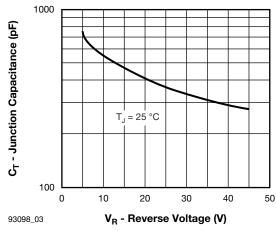


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

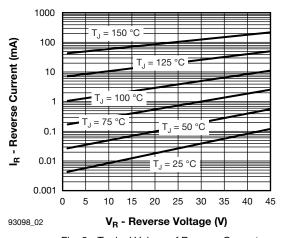


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

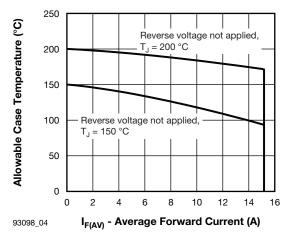


Fig. 4 - Maximum Allowable Case Temperature vs. Average Forward Current

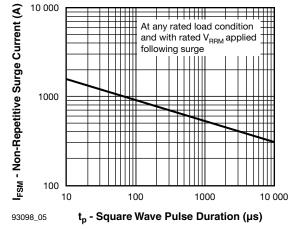


Fig. 5 - Maximum Non-Repetitive Surge Current

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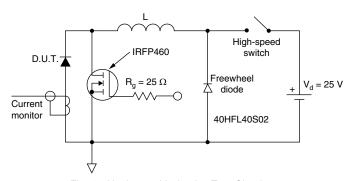
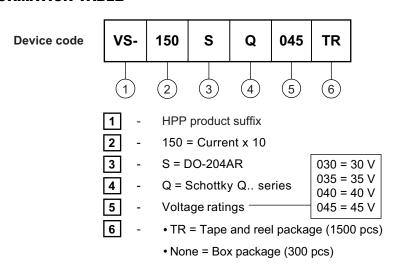


Fig. 6 - Unclamped Inductive Test Circuit

ORDERING INFORMATION TABLE



LINKS TO RELATED DOCUMENTS				
Dimensions <u>www.vishay.com/doc?95243</u>				
Part marking information <u>www.vishay.com/doc?95325</u>				
Packaging information	www.vishay.com/doc?95332			



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